

Notice of References Cited	Application/Control No. 10/509,303		Applicant(s)/Patent Under Reexamination AOKI, SATOSHI	
	Examiner SHANNON GARDNER		Art Unit 4132	Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	A	US-4,335,266	06-1982	Mickelsen et al.	136/260
	B	US-			
	C	US-			
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Yamaguchi, Yoshida, Minoura, Structural and compositional analyses on indium sulfide thin films deposited in aqueous chemical bath containing indium chloride and thioacetamide, 2003, Thin Solid Films, 431-432, pp 354-358
	V	Nakada, Furumi, Kunioka, High-Efficiency Cadmium-free Cu(In,Ge)Se ₂ Thin-Film Solar Cells with Chemically Deposited ZnS Buffer Layers, Oct 1999, IEEE Transaction on Electron Devices, Vol 46 No 10, pp 2093-2097
	W	Hashimoto, Kohara, Negami, Nishitani, Wada, Chemical Bath Deposition of CdS buffer layer for CIGS solar cells, 1998, Solar Energy Materials and Solar Cells, 50, pp 71-77
	X	Dona, Herrero, Chemical Bath Deposition of CdS Thin Films: An Approach to the Chemical Mechanism Through Study of the Film Microstructure, 1997, J. Electrochem. Soc., Vol. 144 No. 11, pp 4081-40941

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.